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Andrew P. Knights
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Contents

| | |
|-----|-----------------------------|
| vii | <i>Authors</i> |
| ix | <i>Conference Committee</i> |

MODULATORS

| | |
|----------|---|
| 10108 02 | Passively biased resonantly enhanced silicon photonics modulator with high optical bandwidth (Invited Paper) [10108-1] |
| 10108 04 | Numerical analysis and optimization of high-speed silicon microring resonator modulators using high-performance carrier-depletion phase shifters [10108-3] |
| 10108 05 | All-optical switch with 1 ps response time enabled by graphene oxide infiltrated subwavelength grating waveguide [10108-4] |

WAVEGUIDE DEVICES I

| | |
|----------|--|
| 10108 08 | Silicon photonic device applications using micro-opto-electro-mechanical index perturbation [10108-7] |
| 10108 0A | Broadband silicon bridge waveguide polarization beam splitter [10108-9] |
| 10108 0B | Second order add/drop filter with a single ring resonator [10108-10] |

LIGHT EMISSION I

| | |
|----------|--|
| 10108 0C | Inductively coupled plasma etching of germanium tin for the fabrication of photonic components [10108-12] |
| 10108 0D | Luminescence of strained Ge on GeSn virtual substrate grown on Si (001) [10108-13] |
| 10108 0E | Laser and transistor material on Si substrate [10108-14] |

SILICON-PHOTONIC SYSTEMS I

| | |
|----------|---|
| 10108 0K | High-brightness lasers on silicon by beam combining (Invited Paper) [10108-19] |
| 10108 0L | Thermal stress in an optical silica fiber embedded (soldered) into silicon [10108-20] |
| 10108 0M | Development of new MPPC with higher NIR sensitivity and wider dynamic range [10108-21] |

10108 0N **Design of an 8-tap CMOS lock-in pixel with lateral electric field charge modulator for highly time-resolved imaging** [10108-22]

SILICON-PHOTONIC SYSTEMS II

10108 0O **Energy-efficient millimeter-wave generation using silicon photonics (Invited Paper)** [10108-23]

10108 0P **Miniature, low-cost, 200 mW, infrared thermal emitter sealed by wafer-level bonding** [10108-24]

10108 0Q **CMOS-compatible optical AND, OR, and XOR gates using voltage-induced free-carrier dispersion and stimulated Raman scattering** [10108-25]

WAVEGUIDE DEVICES II

10108 0V **Fabrication tolerant flat-top interleavers** [10108-30]

10108 0W **Analytical model for the analysis of the electromagnetic field in grating couplers** [10108-31]

SILICON-BASED OPTICAL SENSORS

10108 0X **A high-efficiency low-noise signal amplification mechanism for photodetectors (Invited Paper)** [10108-32]

10108 0Y **Silicon hybrid SPAD with high-NIR-sensitivity for TOF applications** [10108-33]

10108 0Z **Photonic integrated circuits for multi-color laser engines** [10108-34]

10108 10 **High-Q resonance near zero wave vector in photonic crystal slab for label-free sensing** [10108-35]

10108 11 **Ultra-sensitive silicon-photonic on-chip sensor using microfabrication technology** [10108-36]

MID-IR SILICON PHOTONICS

10108 12 **Ge-rich SiGe waveguides for mid-infrared photonics (Invited Paper)** [10108-37]

10108 13 **Silicon-based $\text{Ge}_{0.89}\text{Sn}_{0.11}$ photodetector and light emitter towards mid-infrared applications (Invited Paper)** [10108-38]

10108 14 **Mid-infrared SOI micro-ring modulator operating at 2.02 microns** [10108-39]

FABRICATION AND MANUFACTURING OF SILICON PHOTONICS

- 10108 16 **Improvement of sidewall roughness of sub-micron silicon-on-insulator waveguides for low-loss on-chip links** [10108-42]
- 10108 17 **Towards autonomous testing of photonic integrated circuits** [10108-43]
- 10108 19 **Integration and modeling of photonic devices suitable for high performance computing and data center applications** [10108-45]

LIGHT EMISSION II

- 10108 1A **Integrating III-V quantum dot lasers on silicon substrates for silicon photonics (Invited Paper)** [10108-11]
- 10108 1B **High-quality and homogeneous 200-mm GeOI wafers processed for high strain induction in Ge** [10108-46]
- 10108 1C **Optical study of strain-free GeSn nanowires** [10108-47]

POSTER SESSION

- 10108 1E **Bandwidth and center wavelength tunable micro-ring optical filter with Vernier effect by four spectrum combination** [10108-51]
- 10108 1F **Dynamic routing control through bends for Si sub-micrometer optical interconnects** [10108-52]
- 10108 1G **Diffusion doped plasma dispersion silicon modulators** [10108-54]
- 10108 1J **Photonic crystal ring resonator: a promising device for a multitude of applications** [10108-57]
- 10108 1N **Dynamic optical control of silicon nanoparticle scattering in the near and mid-IR** [10108-61]

Authors

Numbers in the index correspond to the last two digits of the seven-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first five digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Aalto, Timo, 0B, 0V
Adachi, Shunsuke, 0Y
Al-Kabi, Sattar, 13
Ang, Thomas Y. L., 04, 0A
Aubin, J., 0C
Awtry, Z. M., 08
Ayoub, Ahmad B., 11
Baba, Takashi, 0Y
Bakke, K. A. H., 0P
Ballabio, Andrea, 12
Beausoleil, Ray, 19
Bechler, Stefan, 0D
Bellegarde, Cyril, 16
Bertrand, M., 1B
Biswas, Subhajit, 1C
Blampey, B., 19
Boeke, Julia, 0W
Bowers, John E., 0K
Brisson, S., 19
Büscher, Martin, 0Z
Calvo, V., 0C, 1B
Cao, Wei, 17
Carras, Mathieu, 12
Chaisakul, Papichaya, 12
Chelnokov, A., 0C, 1B
Chen, Chin-Hui, 19
Chen, G. F. R., 0A
Chen, Ray T., 05
Chen, S., 1A
Chen, Xia, 17
Cherchi, Matteo, 0B, 0V
Chrastina, Daniel, 12
Chu, Hong Son, 0A
Clavel, Michael B., 0E
Dai, Tingge, 1E
Das, Partha P., 1J
Davenport, Michael L., 0K
Descos, A., 19
Doherty, Jessica, 1C
Dorostkar, Ali, 0W
Dow, Liam G. R., 14
Du, Wei, 13
Duchemin, I., 1B
El Shamy, Raghi, 1N
Faist, J., 1B
Fiorentino, M., 19
Frigerio, Jacopo, 12
Gassenq, A., 0C, 1B
Gays, F., 19
Geuzebroek, Douwe, 0Z
Ghetmiri, Seyed, 13
Gilles, Clément, 12
Gjessing, J., 0P
Goetz, P. G., 08
Gostimirovic, Dusan, 0Q
Guilloy, K., 0C, 1B
Hadzialic, S., 0P
Hagan, David E., 14
Hall, David, 0X
Harjanne, Mikko, 0B, 0V
Hartmann, Jean-Michel, 0C, 16, 1B
Heck, Martijn J. R., 0O
Hegde, Gopalkrishna, 1J
Holmes, Justin D., 1C
Hudait, Mantu K., 0E
Hughes, Vincent, 16
Isella, Giovanni, 12
Ishida, Atsushi, 0M, 0Y
Ismail, Yehea, 1F, 1N
Jamshidi, Kambiz, 0W
Jeyaselvan, Vadivukkarasi, 1G
Jia, Baohua, 05
John, Kamal, 1J
Kagawa, Keiichiro, 0N
Kandoth, Anusree, 1J
Kapulainen, Markku, 0B, 0V
Kawahito, Shoji, 0N
Kennedy, K., 1A
Khokhar, Ali Z., 17
Kittler, Martin, 0D
Klein, Edwin, 0Z
Klos, Thomas, 0Z
Knights, Andrew P., 14
Koerner, Roman, 0D
Kopp, C., 19
Kozak, D. A., 08
Krieg, Jürgen, 0Z
Kumar, Resmi R., 1J
Le Roux, Xavier, 12
Leisching, Patrick, 0Z
Leuermann, Jonas, 0Z
Li, Baohua, 13
Li, W., 1A
Liao, M., 1A
Lim, Soon Thor, 04, 0A
Liu, H., 1A
Liu, Qiankun, 12
Liu, Yonghao, 10

Liu, Yu-Hsin, 0X
 Lo, Yu-Hwa, 0X
 Lyan, Philippe, 16
 Mahon, R., 08
 Maisons, Grégory, 12
 Margetis, Joe, 13
 Marris-Morini, Delphine, 12
 Mehrabkhani, Soheil, 0W
 Mekawey, Hosam, 1F, 1N
 Merget, Florian, 02
 Milord, L., 0C
 Milosevic, Milan M., 17
 Mohammadhosseini, Hakimeh, 0O
 Mortazavi, Mansour, 13
 Moscoso-Mártir, Alvaro, 02
 Mosleh, Aboozar, 13
 Murphy Armando, Felipe, 0E
 Myko, A., 19
 Nagano, Terumasa, 0M, 0Y
 Nageeb, Ahmed, 1N
 Nakamura, Shigeyuki, 0Y
 Naseem, Hameed, 13
 Niaz, Iffikhar Ahmad, 0X
 Niquet, Y. M., 1B
 Nojic, Jovana, 02
 Ochalski, Tomasz J., 0E, 1C
 Oehme, Michael, 0D
 Ong, Jun Rong, 0A
 Osman, Abdelrahman, 1N
 Pan, Zeyu, 05
 Panuski, C. L., 08
 Pargon, Erwine, 16
 Park, D., 08
 Pauc, N., 0C, 1B
 Pawlina, Bryan, 0A
 Petit-Etienne, Camille, 16
 Pham, Thach, 13
 Png, Ching Eng, 04, 0A
 Pruessner, M. W., 08
 Rabinovich, W. S., 08
 Raihan Miah, Mohammad Abu, 0X
 Ramakrishnan, Rohit K., 1J
 Ramírez, Joan Manel, 12
 Reboud, V., 0C, 1B
 Reed, Graham T., 17
 Rieutord, F., 1B
 Romero-García, Sebastian, 02, 0Z
 Ross, I., 1A
 Rothman, J., 0C, 1B
 Rouchon, D., 1B
 S., Mohan, 1J
 Sahin, Ezgi, 0A
 Saladukha, Dzianis, 0E, 1C
 Schjølberg-Henriksen, K., 0P
 Schneider, Thomas, 0W
 Schulze, Jörg, 0D
 Schwartz, Bernhard, 0D
 Sciancalepore, Corrado, 16
 Seeds, A., 1A
 Selvaraja, Shankar Kumar, 1G
 Seo, Min-Woong, 0N
 Seyedi, M. A., 19
 Sharif Azadeh, Saeed, 02
 Shen, Ao, 1E
 Shen, Bin, 02
 Shirakawa, Yuya, 0N
 Shoer, Ibrahim, 1N
 Sigg, H., 1B
 Soref, Richard, 13
 Spott, Alexander, 0K
 Srinivas, T., 1J
 Stanton, Eric J., 0K
 Stievater, T. H., 08
 Suhir, E., 0L
 Sun, Fei, 0B, 0V
 Sun, Greg, 13
 Sun, Yuze, 10
 Swillam, Mohamed A., 11, 1F, 1N
 Szelag, B., 19
 T. R., Yadunath, 1J
 T., Badrinarayana, 1J
 T., Sreenivasulu, 1J
 Tan, D. T. H., 0A
 Tang, M., 1A
 Tardif, S., 0C, 1B
 Teranishi, Nobukazu, 0N
 Tharwat, Christen, 1N
 Thomson, David J., 17
 Tolle, John, 13
 Tran, Huong, 13
 Tsuchiya, Ryutaro, 0M
 Vakarin, Vladyslav, 12
 van Kerkhof, Joost, 0Z
 Vehmas, Tapani, 0B, 0V
 Vivien, Laurent, 12
 Volet, Nicolas, 0K
 Wang, D. T., 0P
 Wang, Gencheng, 1E
 Wang, Shuling, 10
 Wang, Yaguo, 05
 Widiez, J., 1B
 Witzens, Jeremy, 02, 0Z
 Wu, J., 1A
 Xu, Xiaochuan, 05
 Yamamoto, Koei, 0M, 0Y
 Yang, Jianyi, 1E
 Yasutomi, Keita, 0N
 Ye, Winnie N., 0Q
 Yi, S., 0L
 Yu, Shui-Qing, 13
 Zabel, T., 1B
 Zhan, Shijie, 1E
 Zhou, Weidong, 10
 Zhou, Yiyin, 13

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- 4 Silicon-based Optical Interconnects
Andrew P. Knights, McMaster University (Canada)
- 5 Silicon-Photonic Systems I
Graham T. Reed, Optoelectronics Research Centre (United Kingdom)
- 6 Silicon-Photonic Systems II
Andrew P. Knights, McMaster University (Canada)
- 7 Waveguide Devices II
Jeremy Witzens, RWTH Aachen University (Germany)
- 8 Silicon-based Optical Sensors
Delphine Marris-Morini, Institut d'Électronique Fondamentale (France)
- 9 Mid-IR Silicon Photonics
Frederic Y. Gardes, University of Southampton (United Kingdom)
- 10 Fabrication and Manufacturing of Silicon Photonics
Jonathan D. B. Bradley, McMaster University (Canada)
- 11 Light Emission II
Graham T. Reed, Optoelectronics Research Centre (United Kingdom)